

		UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement											
LTE Band 41 5MHz QPSK		Company: Samsung											
		Project #: 16K23557											
		Date: 06-15-16											
		Test Engineer: JH Park											
		Configuration: EUT / AC Adapter, X Position											
		Mode: TX, LTE BAND 41, 5MHz BW, QPSK											
				Chamber		Pre-amplifier		Filter		Limit			
				Chamber 2		AFS42		Filter 1		FCC Part 27			
				f GHz	SGreading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	ERP (dBm)	Limit (dBm)	Delta (dB)	Notes
				Low Ch, (2557.5 MHz)									
				5.1150	-8.5	V	3.0	40.9	1.0	-48.4	-25.0	-23.4	
				7.6725	-9.2	V	3.0	40.6	1.0	-48.9	-25.0	-23.9	
				10.2300	-4.2	V	3.0	39.5	1.0	-42.7	-25.0	-17.7	
				5.1150	-8.9	H	3.0	40.9	1.0	-48.8	-25.0	-23.8	
				7.6725	-12.9	H	3.0	40.6	1.0	-52.6	-25.0	-27.6	
				10.2300	-9.9	H	3.0	39.5	1.0	-48.4	-25.0	-23.4	
				Mid Ch, (2605 MHz)									
				5.2100	1.0	V	3.0	40.9	1.0	-38.9	-25.0	-13.9	
				7.8150	-11.9	V	3.0	40.6	1.0	-51.4	-25.0	-26.4	
				10.4200	3.0	V	3.0	39.4	1.0	-35.4	-25.0	-10.4	
				5.2100	-0.3	H	3.0	40.9	1.0	-40.2	-25.0	-15.2	
				7.8150	-9.8	H	3.0	40.6	1.0	-49.4	-25.0	-24.4	
				10.4200	-4.1	H	3.0	39.4	1.0	-42.5	-25.0	-17.5	
				High Ch, (2652.5 MHz)									
		5.3050	-0.6	V	3.0	40.9	1.0	-40.5	-25.0	-15.5			
		7.9575	-12.1	V	3.0	40.5	1.0	-51.5	-25.0	-26.5			
		10.6100	-6.2	V	3.0	39.2	1.0	-44.4	-25.0	-19.4			
		5.3050	-4.4	H	3.0	40.9	1.0	-44.3	-25.0	-19.3			
		7.9575	-11.2	H	3.0	40.5	1.0	-50.6	-25.0	-25.6			
		10.6100	-10.4	H	3.0	39.2	1.0	-48.6	-25.0	-23.6			
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											
LTE Band 41 5MHz 16QAM		Company: Samsung											
		Project #: 16K23557											
		Date: 06-15-16											
		Test Engineer: JH Park											
		Configuration: EUT / AC Adapter, X Position											
		Mode: TX, LTE BAND 41, 5MHz BW, 16QAM											
				Chamber		Pre-amplifier		Filter		Limit			
				Chamber 2		AFS42		Filter 1		FCC Part 27			
				f GHz	SGreading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	ERP (dBm)	Limit (dBm)	Delta (dB)	Notes
				Low Ch, (2560 MHz)									
				5.1200	-8.3	V	3.0	40.9	1.0	-48.2	-25.0	-23.2	
				7.6800	-9.1	V	3.0	40.6	1.0	-48.7	-25.0	-23.7	
				10.2400	-4.9	V	3.0	39.5	1.0	-43.5	-25.0	-18.5	
				5.1200	-9.6	H	3.0	40.9	1.0	-49.5	-25.0	-24.5	
				7.6800	-12.0	H	3.0	40.6	1.0	-51.6	-25.0	-26.6	
				10.2400	-9.8	H	3.0	39.5	1.0	-48.3	-25.0	-23.3	
				Mid Ch, (2605 MHz)									
				5.2100	0.9	V	3.0	40.9	1.0	-39.0	-25.0	-14.0	
				7.8150	-12.2	V	3.0	40.6	1.0	-51.7	-25.0	-26.7	
				10.4200	3.4	V	3.0	39.4	1.0	-35.0	-25.0	-10.0	
				5.2100	-0.8	H	3.0	40.9	1.0	-40.7	-25.0	-15.7	
				7.8150	-9.8	H	3.0	40.6	1.0	-49.3	-25.0	-24.3	
				10.4200	-4.7	H	3.0	39.4	1.0	-43.1	-25.0	-18.1	
				High Ch, (2652.5 MHz)									
		5.3050	-0.8	V	3.0	40.9	1.0	-40.7	-25.0	-15.7			
		7.9575	-12.6	V	3.0	40.5	1.0	-52.1	-25.0	-27.1			
		10.6100	-5.5	V	3.0	39.2	1.0	-43.7	-25.0	-18.7			
		5.3050	-2.9	H	3.0	40.9	1.0	-42.8	-25.0	-17.8			
		7.9575	-12.4	H	3.0	40.5	1.0	-51.9	-25.0	-26.9			
		10.6100	-9.4	H	3.0	39.2	1.0	-47.7	-25.0	-22.7			
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											

LTE Band 5

		UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement										
LTE Band 5 10MHz QPSK	Company: Samsung Project #: 16K23557 Date: 06-22-16 Test Engineer: YH Lim Configuration: EUT / AC Adapter, X Position Mode: TX, LTE BAND 5, 10MHz BW, QPSK		Chamber: Chamber 2		Pre-amplifier: AFS42		Filter: Filter 1		Limit: Part 22			
			f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
			Low Channel (829MHz)									
			1.6580	-10.1	V	3.0	39.1	1.0	-48.2	-13.0	-35.2	
			2.4870	-13.2	V	3.0	39.5	1.0	-51.7	-13.0	-38.7	
			3.3160	-19.9	V	3.0	40.1	1.0	-59.0	-13.0	-46.0	
			1.6580	-11.0	H	3.0	39.1	1.0	-49.1	-13.0	-36.1	
			2.4870	-13.0	H	3.0	39.5	1.0	-51.5	-13.0	-38.5	
			3.3160	-20.9	H	3.0	40.1	1.0	-60.1	-13.0	-47.1	
			Mid Channel (836.5MHz)									
			1.6730	-14.2	V	3.0	39.1	1.0	-52.3	-13.0	-39.3	
			2.5095	-11.7	V	3.0	39.5	1.0	-50.3	-13.0	-37.3	
			3.3460	-20.8	V	3.0	40.1	1.0	-59.9	-13.0	-46.9	
			1.6730	-12.8	H	3.0	39.1	1.0	-50.9	-13.0	-37.9	
			2.5095	-6.0	H	3.0	39.5	1.0	-44.5	-13.0	-31.5	
		3.3460	-21.0	H	3.0	40.1	1.0	-60.2	-13.0	-47.2		
		High Channel (844MHz)										
		1.6880	-18.5	V	3.0	39.1	1.0	-56.6	-13.0	-43.6		
		2.5320	-14.7	V	3.0	39.5	1.0	-53.2	-13.0	-40.2		
		3.3760	-21.2	V	3.0	40.2	1.0	-60.4	-13.0	-47.4		
		1.6880	-17.0	H	3.0	39.1	1.0	-55.2	-13.0	-42.2		
		2.5320	-10.6	H	3.0	39.5	1.0	-49.2	-13.0	-36.2		
		3.3760	-21.4	H	3.0	40.2	1.0	-60.6	-13.0	-47.6		
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										
LTE Band 5 10MHz 16QAM	Company: Samsung Project #: 16K23557 Date: 06-22-16 Test Engineer: YH Lim Configuration: EUT / AC Adapter, X Position Mode: TX, LTE BAND 5, 10MHz BW, 16QAM		Chamber: Chamber 2		Pre-amplifier: AFS42		Filter: Filter 1		Limit: Part 22			
			f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes
			Low Channel (829MHz)									
			1.6580	-10.5	V	3.0	39.1	1.0	-48.6	-13.0	-35.6	
			2.4870	-14.3	V	3.0	39.5	1.0	-52.9	-13.0	-39.9	
			3.3160	-20.5	V	3.0	40.1	1.0	-59.6	-13.0	-46.6	
			1.6580	-11.4	H	3.0	39.1	1.0	-49.5	-13.0	-36.5	
			2.4870	-15.1	H	3.0	39.5	1.0	-53.6	-13.0	-40.6	
			3.3160	-20.9	H	3.0	40.1	1.0	-60.0	-13.0	-47.0	
			Mid Channel (836.5MHz)									
			1.6730	-14.9	V	3.0	39.1	1.0	-53.0	-13.0	-40.0	
			2.5090	-12.8	V	3.0	39.5	1.0	-51.3	-13.0	-38.3	
			3.3460	-20.4	V	3.0	40.1	1.0	-59.5	-13.0	-46.5	
			1.6730	-12.9	H	3.0	39.1	1.0	-51.0	-13.0	-38.0	
			2.5090	-7.4	H	3.0	39.5	1.0	-45.9	-13.0	-32.9	
		3.3460	-20.8	H	3.0	40.1	1.0	-59.9	-13.0	-46.9		
		High Channel (844MHz)										
		1.6880	-17.7	V	3.0	39.1	1.0	-55.8	-13.0	-42.8		
		2.5320	-15.8	V	3.0	39.5	1.0	-54.4	-13.0	-41.4		
		3.3760	-20.5	V	3.0	40.2	1.0	-59.6	-13.0	-46.6		
		1.6880	-19.0	H	3.0	39.1	1.0	-57.1	-13.0	-44.1		
		2.5320	-15.1	H	3.0	39.5	1.0	-53.6	-13.0	-40.6		
		3.3760	-21.6	H	3.0	40.2	1.0	-60.8	-13.0	-47.8		
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.										

		UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement										
LTE Band 5 5MHz QPSK	Company: Samsung											
	Project #: 16K23557											
	Date: 06-22-16											
	Test Engineer: YH Lim											
	Configuration: EUT / AC Adapter, X Position											
	Mode: TX LTE BAND 5, 5MHz BW,QPSK											
	Chamber		Pre-amplifier		Filter		Limit					
	Chamber 2		AFS42		Filter 1		Part 22					
	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes		
	Low Channel (826.5MHz)											
	1.6530	-11.0	V	3.0	39.1	1.0	-49.1	-13.0	-36.1			
	2.4790	-11.5	V	3.0	39.5	1.0	-50.0	-13.0	-37.0			
	3.3060	-20.2	V	3.0	40.1	1.0	-59.3	-13.0	-46.3			
	1.6530	-14.9	H	3.0	39.1	1.0	-53.1	-13.0	-40.1			
	2.4790	-7.2	H	3.0	39.5	1.0	-45.7	-13.0	-32.7			
	3.3060	-21.0	H	3.0	40.1	1.0	-60.1	-13.0	-47.1			
	Mid Channel (836.5MHz)											
	1.6730	-14.2	V	3.0	39.1	1.0	-52.3	-13.0	-39.3			
	2.5090	-12.5	V	3.0	39.5	1.0	-51.0	-13.0	-38.0			
	3.3460	-20.2	V	3.0	40.1	1.0	-59.3	-13.0	-46.3			
	1.6730	-12.2	H	3.0	39.1	1.0	-50.3	-13.0	-37.3			
	2.5090	-5.7	H	3.0	39.5	1.0	-44.2	-13.0	-31.2			
	3.3460	-21.1	H	3.0	40.1	1.0	-60.2	-13.0	-47.2			
	High Channel (846.5MHz)											
1.6930	-16.5	V	3.0	39.1	1.0	-54.6	-13.0	-41.6				
2.5390	-12.4	V	3.0	39.6	1.0	-50.9	-13.0	-37.9				
3.3860	-20.4	V	3.0	40.2	1.0	-59.6	-13.0	-46.6				
1.6930	-15.2	H	3.0	39.1	1.0	-53.3	-13.0	-40.3				
2.5390	-7.5	H	3.0	39.6	1.0	-46.0	-13.0	-33.0				
3.3860	-21.0	H	3.0	40.2	1.0	-60.2	-13.0	-47.2				
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.												
LTE Band 5 5MHz 16QAM	UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement											
	Company: Samsung											
	Project #: 16K23557											
	Date: 06-22-16											
	Test Engineer: YH Lim											
	Configuration: EUT / AC Adapter, X Position											
	Mode: TX LTE BAND 5, 5MHz BW,16QAM											
	Chamber		Pre-amplifier		Filter		Limit					
	Chamber 2		AFS42		Filter 1		Part 22					
	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes		
	Low Channel (826.5MHz)											
	1.6530	-10.6	V	3.0	39.1	1.0	-48.7	-13.0	-35.7			
	2.4790	-11.3	V	3.0	39.5	1.0	-49.8	-13.0	-36.8			
	3.3060	-20.2	V	3.0	40.1	1.0	-59.3	-13.0	-46.3			
	1.6530	-16.2	H	3.0	39.1	1.0	-54.3	-13.0	-41.3			
	2.4790	-6.4	H	3.0	39.5	1.0	-44.9	-13.0	-31.9			
	3.3060	-21.0	H	3.0	40.1	1.0	-60.2	-13.0	-47.2			
	Mid Channel (836.5MHz)											
	1.6730	-15.9	V	3.0	39.1	1.0	-54.0	-13.0	-41.0			
	2.5090	-12.9	V	3.0	39.5	1.0	-51.4	-13.0	-38.4			
	3.3460	-20.3	V	3.0	40.1	1.0	-59.4	-13.0	-46.4			
	1.6730	-13.4	H	3.0	39.1	1.0	-51.5	-13.0	-38.5			
	2.5090	-5.6	H	3.0	39.5	1.0	-44.1	-13.0	-31.1			
	3.3460	-21.4	H	3.0	40.1	1.0	-60.6	-13.0	-47.6			
High Channel (846.5MHz)												
1.6930	-16.8	V	3.0	39.1	1.0	-54.9	-13.0	-41.9				
2.5390	-11.8	V	3.0	39.6	1.0	-50.3	-13.0	-37.3				
3.3860	-20.8	V	3.0	40.2	1.0	-60.0	-13.0	-47.0				
1.6930	-15.4	H	3.0	39.1	1.0	-53.5	-13.0	-40.5				
2.5390	-5.8	H	3.0	39.6	1.0	-44.3	-13.0	-31.3				
3.3860	-21.0	H	3.0	40.2	1.0	-60.2	-13.0	-47.2				
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.												

		UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement											
LTE Band 5 3MHz QPSK	Company: Samsung Project #: 16K23557 Date: 06-22-16 Test Engineer: YH Lim Configuration: EUT / AC Adapter, X Position Mode: TX LTE BAND 5, 3MHz BW, QPSK		Chamber Chamber 2		Pre-amplifier AFS42		Filter Filter 1		Limit Part 22				
			f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes	
			Low Channel (825.5MHz)										
			1.6510	-13.1	V	3.0	39.1	1.0	-51.2	-13.0	-38.2		
			2.4765	-5.2	V	3.0	39.5	1.0	-43.7	-13.0	-30.7		
			3.3020	-19.9	V	3.0	40.1	1.0	-59.0	-13.0	-46.0		
			1.6510	-9.3	H	3.0	39.1	1.0	-47.4	-13.0	-34.4		
			2.4765	-1.4	H	3.0	39.5	1.0	-39.9	-13.0	-26.9		
			3.3020	-20.7	H	3.0	40.1	1.0	-59.8	-13.0	-46.8		
			Mid Channel (836.5MHz)										
			1.6730	-13.8	V	3.0	39.1	1.0	-51.9	-13.0	-38.9		
			2.5090	-4.9	V	3.0	39.5	1.0	-43.4	-13.0	-30.4		
			3.3460	-19.7	V	3.0	40.1	1.0	-58.8	-13.0	-45.8		
			1.6730	-8.1	H	3.0	39.1	1.0	-46.3	-13.0	-33.3		
			2.5090	-0.8	H	3.0	39.5	1.0	-39.4	-13.0	-26.4		
		3.3460	-21.5	H	3.0	40.1	1.0	-60.6	-13.0	-47.6			
		High Channel (847.5MHz)											
		1.6950	-17.6	V	3.0	39.1	1.0	-55.7	-13.0	-42.7			
		2.5425	-5.6	V	3.0	39.6	1.0	-44.1	-13.0	-31.1			
		3.3900	-19.9	V	3.0	40.2	1.0	-59.1	-13.0	-46.1			
		1.6950	-10.1	H	3.0	39.1	1.0	-48.2	-13.0	-35.2			
		2.5425	-3.6	H	3.0	39.6	1.0	-42.1	-13.0	-29.1			
		3.3900	-20.3	H	3.0	40.2	1.0	-59.5	-13.0	-46.5			
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											
LTE Band 5 3MHz 16QAM	Company: Samsung Project #: 16K23557 Date: 06-22-16 Test Engineer: YH Lim Configuration: EUT / AC Adapter, X Position Mode: TX LTE BAND 5, 3MHz BW, 16QAM		Chamber Chamber 2		Pre-amplifier AFS42		Filter Filter 1		Limit Part 22				
			f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes	
			Low Channel (825.5MHz)										
			1.6510	-12.3	V	3.0	39.1	1.0	-50.4	-13.0	-37.4		
			2.4765	-5.2	V	3.0	39.5	1.0	-43.7	-13.0	-30.7		
			3.3020	-20.9	V	3.0	40.1	1.0	-60.0	-13.0	-47.0		
			1.6510	-10.2	H	3.0	39.1	1.0	-48.3	-13.0	-35.3		
			2.4765	-1.5	H	3.0	39.5	1.0	-40.0	-13.0	-27.0		
			3.3020	-21.3	H	3.0	40.1	1.0	-60.4	-13.0	-47.4		
			Mid Channel (836.5MHz)										
			1.6730	-14.1	V	3.0	39.1	1.0	-52.2	-13.0	-39.2		
			2.5090	-5.2	V	3.0	39.5	1.0	-43.7	-13.0	-30.7		
			3.3460	-20.5	V	3.0	40.1	1.0	-59.6	-13.0	-46.6		
			1.6730	-7.3	H	3.0	39.1	1.0	-45.4	-13.0	-32.4		
			2.5090	-0.6	H	3.0	39.5	1.0	-39.1	-13.0	-26.1		
		3.3460	-21.6	H	3.0	40.1	1.0	-60.7	-13.0	-47.7			
		High Channel (847.5MHz)											
		1.6950	-18.2	V	3.0	39.1	1.0	-56.4	-13.0	-43.4			
		2.5425	-7.0	V	3.0	39.6	1.0	-45.6	-13.0	-32.6			
		3.3900	-20.0	V	3.0	40.2	1.0	-59.2	-13.0	-46.2			
		1.6950	-10.4	H	3.0	39.1	1.0	-48.6	-13.0	-35.6			
		2.5425	-3.1	H	3.0	39.6	1.0	-41.7	-13.0	-28.7			
		3.3900	-20.7	H	3.0	40.2	1.0	-59.9	-13.0	-46.9			
		Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											

		UL Korea, Ltd Suwon Laboratory Above 1GHz High Frequency Substitution Measurement									
LTE Band 5 1.4MHz QPSK	Company: Samsung										
	Project #: 16K23557										
	Date: 06-22-16										
	Test Engineer: YH Lim										
	Configuration: EUT / AC Adapter, X Position										
	Mode: TX, LTE BAND 5, 1.4MHz BW, QPSK										
	Chamber: Chamber 2		Pre-amplifier: AFS42		Filter: Filter 1		Limit: Part 22				
	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes	
	Low Channel (824.7MHz)										
	1.6494	-9.3	V	3.0	39.1	1.0	-47.4	-13.0	-34.4		
	2.4741	-8.7	V	3.0	39.5	1.0	-47.2	-13.0	-34.2		
	3.2988	-20.6	V	3.0	40.1	1.0	-59.7	-13.0	-46.7		
	1.6494	-11.4	H	3.0	39.1	1.0	-49.5	-13.0	-36.5		
	2.4741	-2.6	H	3.0	39.5	1.0	-41.1	-13.0	-28.1		
	3.2988	-21.4	H	3.0	40.1	1.0	-60.5	-13.0	-47.5		
	Mid Channel (836.5MHz)										
	1.6730	-13.1	V	3.0	39.1	1.0	-51.2	-13.0	-38.2		
	2.5090	-7.1	V	3.0	39.5	1.0	-45.7	-13.0	-32.7		
	3.3460	-20.5	V	3.0	40.1	1.0	-59.6	-13.0	-46.6		
	1.6730	-13.2	H	3.0	39.1	1.0	-51.3	-13.0	-38.3		
	2.5090	-2.1	H	3.0	39.5	1.0	-40.6	-13.0	-27.6		
	3.3460	-20.8	H	3.0	40.1	1.0	-60.0	-13.0	-47.0		
	High Channel (848.3MHz)										
	1.6966	-14.1	V	3.0	39.1	1.0	-52.3	-13.0	-39.3		
2.5449	-7.7	V	3.0	39.6	1.0	-46.3	-13.0	-33.3			
3.3932	-20.5	V	3.0	40.2	1.0	-59.7	-13.0	-46.7			
1.6966	-11.1	H	3.0	39.1	1.0	-49.2	-13.0	-36.2			
2.5449	-2.9	H	3.0	39.6	1.0	-41.4	-13.0	-28.4			
3.3932	-20.0	H	3.0	40.2	1.0	-59.2	-13.0	-46.2			
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											
LTE Band 5 1.4MHz 16QAM	Company: Samsung										
	Project #: 16K23557										
	Date: 06-22-16										
	Test Engineer: YH Lim										
	Configuration: EUT / AC Adapter, X Position										
	Mode: TX, LTE BAND 5, 1.4MHz BW, 16QAM										
	Chamber: Chamber 2		Pre-amplifier: AFS42		Filter: Filter 1		Limit: Part 22				
	f GHz	SG reading (dBm)	Ant. Pol. (H/V)	Distance (m)	Preamp (dB)	Filter (dB)	EIRP (dBm)	Limit (dBm)	Delta (dB)	Notes	
	Low Channel (824.7MHz)										
	1.6494	-9.4	V	3.0	39.1	1.0	-47.5	-13.0	-34.5		
	2.4741	-8.7	V	3.0	39.5	1.0	-47.2	-13.0	-34.2		
	3.2988	-20.9	V	3.0	40.1	1.0	-60.0	-13.0	-47.0		
	1.6494	-10.9	H	3.0	39.1	1.0	-49.0	-13.0	-36.0		
	2.4741	-2.4	H	3.0	39.5	1.0	-40.9	-13.0	-27.9		
	3.2988	-21.6	H	3.0	40.1	1.0	-60.7	-13.0	-47.7		
	Mid Channel (836.5MHz)										
	1.6730	-13.7	V	3.0	39.1	1.0	-51.8	-13.0	-38.8		
	2.5090	-7.1	V	3.0	39.5	1.0	-45.7	-13.0	-32.7		
	3.3460	-20.7	V	3.0	40.1	1.0	-59.8	-13.0	-46.8		
	1.6730	-13.0	H	3.0	39.1	1.0	-51.1	-13.0	-38.1		
	2.5090	-2.1	H	3.0	39.5	1.0	-40.7	-13.0	-27.7		
	3.3460	-21.0	H	3.0	40.1	1.0	-60.1	-13.0	-47.1		
	High Channel (848.3MHz)										
	1.6966	-14.4	V	3.0	39.1	1.0	-52.5	-13.0	-39.5		
2.5449	-7.2	V	3.0	39.6	1.0	-45.8	-13.0	-32.8			
3.3932	-20.1	V	3.0	40.2	1.0	-59.3	-13.0	-46.3			
1.6966	-12.3	H	3.0	39.1	1.0	-50.4	-13.0	-37.4			
2.5449	-2.9	H	3.0	39.6	1.0	-41.5	-13.0	-28.5			
3.3932	-20.4	H	3.0	40.2	1.0	-59.6	-13.0	-46.6			
Rev. 03.03.09 Note: No other emissions were detected above the system noise floor.											